

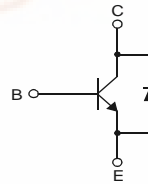
**FAIRCHILD**  
SEMICONDUCTOR®

## FJE5304D

### High Voltage High Speed Power Switch Application

- Wide Safe Operating Area
- Built-in Free Wheeling diode
- Suitable for Electronic Ballast Application
- Small Variance in Storage Time

Equivalent Circuit



1. Emitter 2. Collector 3. Base

### NPN Triple Diffused Planar Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	700	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base Voltage	12	V
$I_C$	Collector Current (DC)	4	A
$I_{CP}$	* Collector Current (Pulse)	8	A
$I_B$	Base Current (DC)	2	A
$I_{BP}$	* Base Current (Pulse)	4	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	30	W
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

\* Pulse Test Pulse Width = 5ms, Duty Cycle  $\geq 1.0\%$

#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = 1\text{mA}, I_E = 0$	700			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 5\text{mA}, I_B = 0$	400			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 1\text{mA}, I_C = 0$	12			V
$I_{CES}$	Collector Cut-off Current	$V_{CE} = 700\text{V}, V_{EB} = 0$			100	mA
$I_{CEO}$	Collector Cut-off Current	$V_{CE} = 400\text{V}, I_B = 0$			250	mA
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 12\text{V}, I_C = 0$			100	mA
$h_{FE}$	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 10\text{mA}$ $V_{CE} = 5\text{V}, I_C = 2\text{A}$	10 8		40	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1\text{A}, I_B = 0.2\text{A}$ $I_C = 2.5\text{A}, I_B = 0.5\text{A}$			0.7 1.0 1.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$ $I_C = 1\text{A}, I_B = 0.2\text{A}$ $I_C = 2.5\text{A}, I_B = 0.5\text{A}$			1.1 1.2 1.3	V
$V_f$	Internal Diode Forward Voltage Drop	$I_f = 2\text{A}$			2.5	V

**Electrical Characteristics** (Continued)  $T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	TYP.	Max.	Units
<b>Inductive Load Switching (<math>V_{CC} = 200\text{V}</math>)</b>						
$t_{stg}$	Storage Time	$I_C = 2\text{A}, I_{B1} = 0.4\text{A}$ $V_{BE}(\text{off}) = -5\text{V},$ $L = 200\mu\text{H}$		0.6		$\mu\text{s}$
$t_f$	Fall Time			0.1		
<b>Resistive Load Switching (<math>V_{CC} = 250\text{V}</math>)</b>						
$t_{stg}$	Storage Time	$I_C = 2\text{A}, I_{B1} = I_{B2} = 0.4\text{A}$ $T_P = 30\mu\text{s}$			2.9	$\mu\text{s}$
$t_f$	Fall Time			0.2		

\* Pulse test:  $PW \leq 300\mu\text{s}$ , Duty cycles  $\leq 2\%$

**Thermal Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	4.17	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	83.3	$^\circ\text{C/W}$

## Typical Characteristics

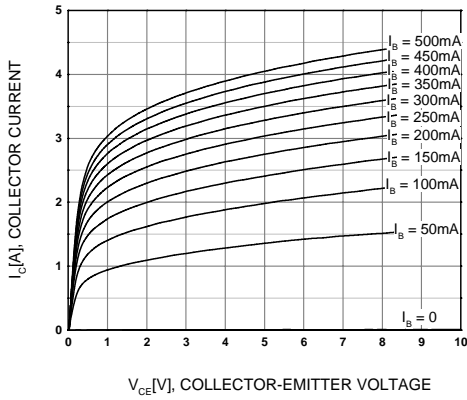


Figure 1. Static Characteristic

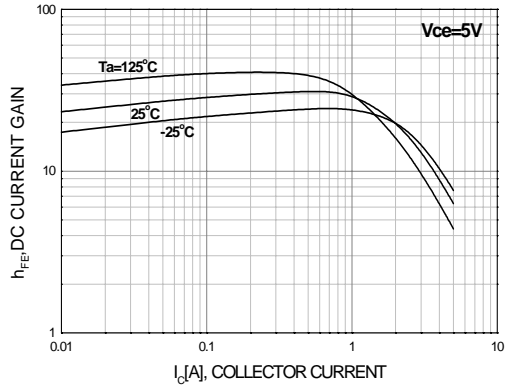


Figure 2. DC Current Gain

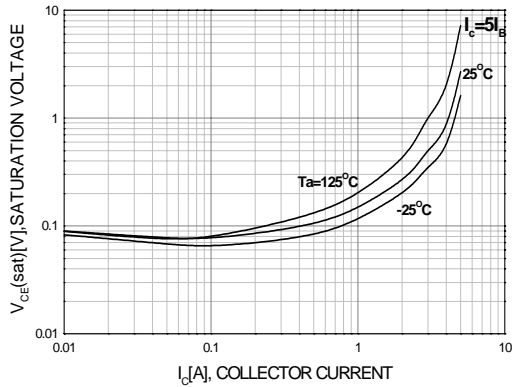


Figure 3. Collector-Emitter Saturation Voltage

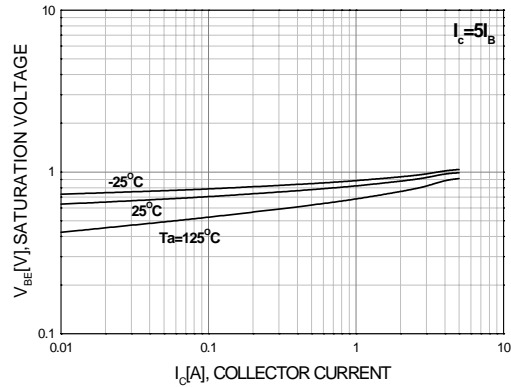


Figure 4. Base-Emitter Saturation Voltage

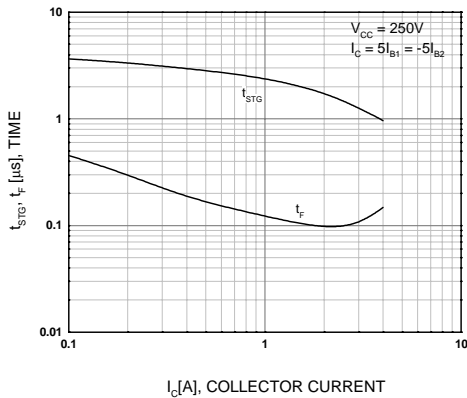


Figure 5. Resistive Load Switching Time

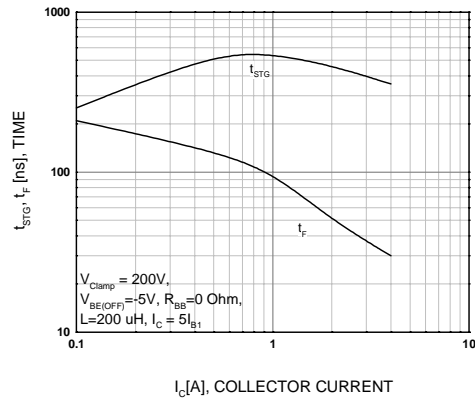


Figure 6. Inductive Load Switching Time

## Typical Characteristics (Continued)

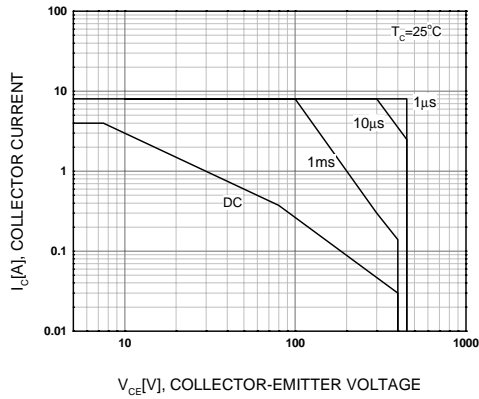


Figure 7. Forward Bias Safe Operating Area

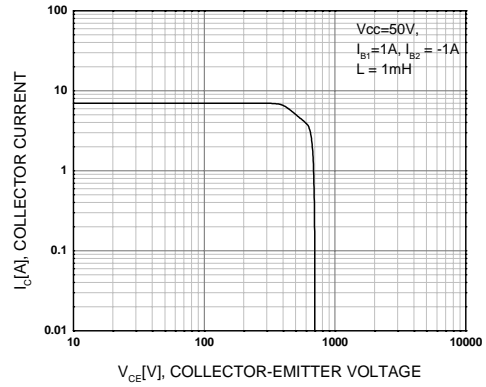


Figure 8. Reverse Bias Safe Operating Area

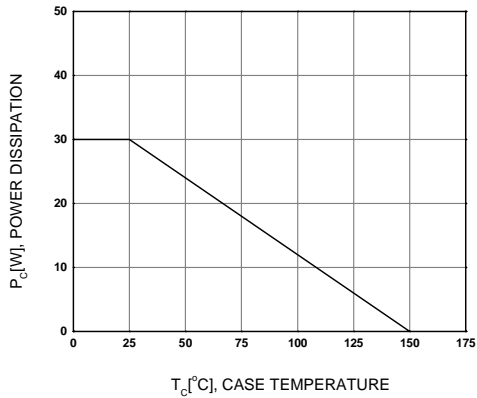
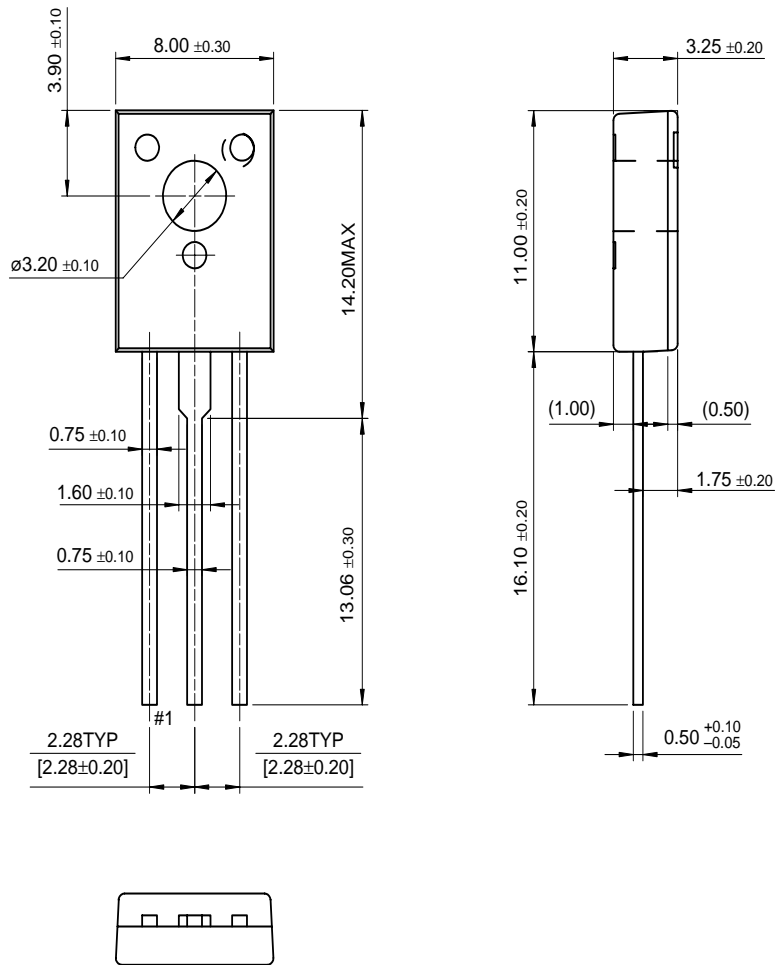


Figure 9. Power Derating

# Package Dimensions

FJE5304D

## TO-126



Dimensions in Millimeters

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CROSSVOLT™	GlobalOptoisolator™	MicroPak™	QS™	SyncFET™
DOME™	GTO™	MICROWIRE™	QT Optoelectronics™	TinyLogic®
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